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www.fairchildsemi.com





H11B815 4-Pin Photodarlington Optocoupler

Description

The H11B815 consists of a gallium arsenide infrared emitting diode driving a silicon Darlington phototransistor in a 4-pin dual in-line package.

Features

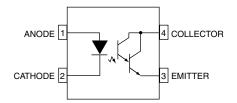
- Compact 4-pin package
- Current Transfer Ratio: 600% minimum (at I_F = 1 mA)
- High isolation voltage between input and output (5300 VRMS)
- UL recognized (File # E90700)

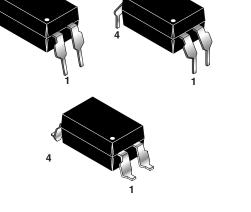
Package

Applications

- Power Supply Monitors
- Relay Contact Monitor
- Telephone/Telegraph Line Receiver
- Twisted Pair Line Receiver
- Digital Logic/Digital Logic

Schematic





Absolute Maximum Ratings (No derating required up to 85°C)

Parameter	Symbol	Value	Units
TOTAL DEVICE			
Storage Temperature	T _{STG}	-55 to +150	°C
Operating Temperature	T _{OPR}	-55 to +100	°C
Lead Solder Temperature	T _{SOL}	260 for 10 sec	°C
Total Device Power Dissipation @ T _A = 25°C	PD	250	mW
EMITTER	•		
DC/Average Forward Input Current	I _F	50	mA
Reverse Input Voltage	V _R	6	V
Forward Current - Peak (1µs pulse, 300pps)	l _F (pk)	1	А
LED Power Dissipation @ T _A = 25°C	PD	70	mW
Derate above 25°C		1.33	mW/°C
DETECTOR			
Collector-Emitter Voltage	V _{CEO}	35	V
Emitter-Collector Voltage	V _{ECO}	6	V
Continuous Collector Current	Ι _C	80	mA
Detector Power Dissipation @ $T_A = 25^{\circ}C$	PD	150	mW
Derate above 25°C		2.0	mW/°C

Electrical Characteristics (T_A = 25°C Unless otherwise specified.) **Individual Component Characteristics**

Parameter	Test Conditions	Symbol	Min	Typ**	Мах	Unit
EMITTER						
Input Forward Voltage	(I _F = 20 mA)	V _F		1.2	1.50	V
Reverse Leakage Current	(V _R = 6.0 V)	I _R		0.001	10	μA
DETECTOR			•			
Collector-Emitter Breakdown Voltage	(I _C = 1.0 mA, I _F = 0)	BV _{CEO}	35	60		V
Emitter-Collector Breakdown Voltage	(I _E = 100 μA, I _F = 0)	BV _{ECO}	6	8		V
Collector-Emitter Dark Current	(V _{CE} = 10 V, I _F = 0)	I _{CEO}		0.005	1	μA
Capacitance	(V _{CE} = 0 V, f = 1 MHz)	C _{CE}		8		pF

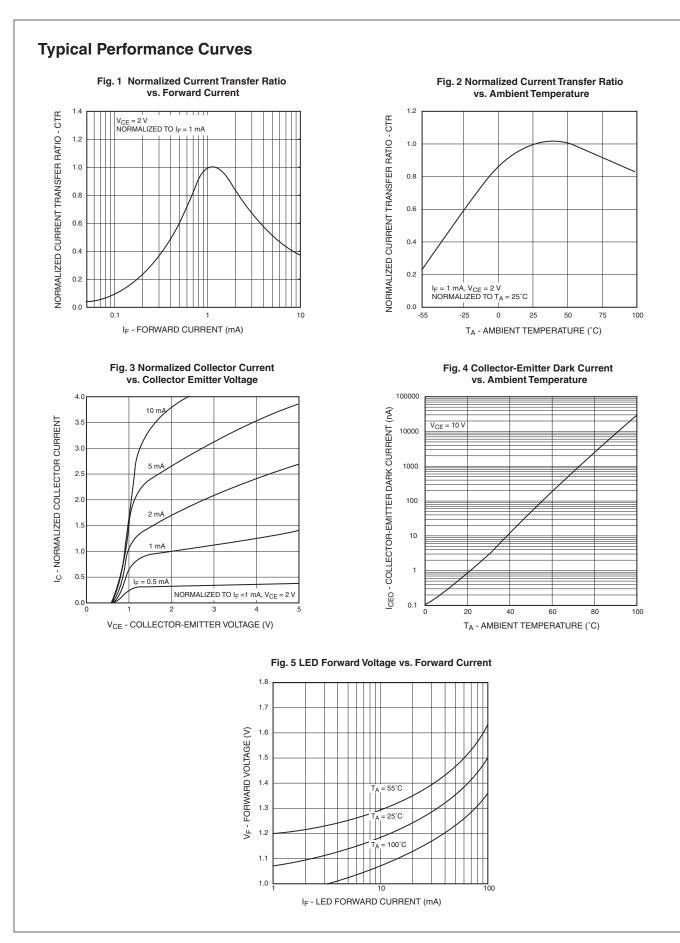
Transfer Characteristics

DC Characteristic	Test Conditions	Symbol	Min	Typ**	Мах	Units
Current Transfer Ratio, Collector-Emitter	(I _F = 1 mA, V _{CE} = 2 V)	CTR	600		7,500	%
Saturation Voltage	(I _F = 20 mA, I _C = 5 mA)	V _{CE(sat)}		0.8	1.0	V
Rise Time (non saturated)	$(I_{C} = 10 \text{ mA}, V_{CE} = 2 \text{ V}, \text{ R}_{L} = 100 \text{ V})$	t _r			300	μs
Fall Time (non saturated)	$(I_{C} = 10 \text{ mA}, V_{CE} = 2 \text{ V}, R_{L} = 100 \text{ V})$	t _f			250	μs

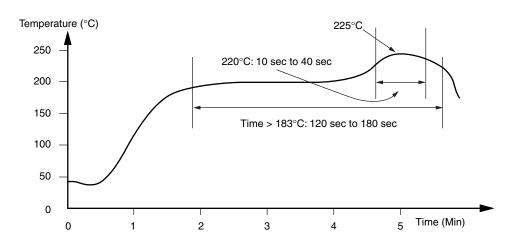
Isolation Characteristics

Characteristic	Test Conditions	Symbol	Min	Typ**	Max	Units
Input-Output Isolation Voltage	(Ι _{Ι-Ο} [1 μΑ, 1 min.)	V _{ISO}	5000			Vac(rms)
Isolation Resistance	(V _{I-O} = 500 VDC)	R _{ISO}	10 ¹¹			Ω
Isolation Capacitance	(V _{I-O} = &, f = 1 MHz)	C _{ISO}		0.5		pf

** All typicals at TA = 25°C

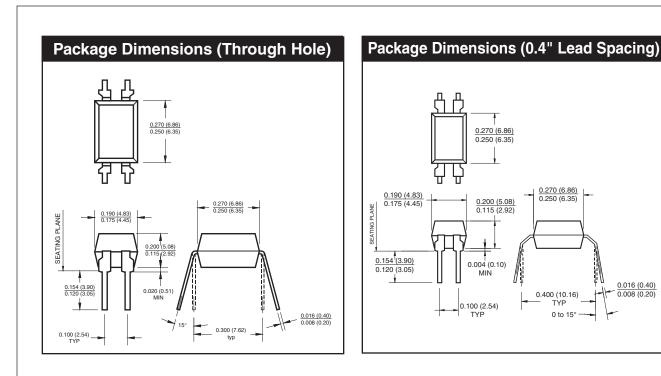


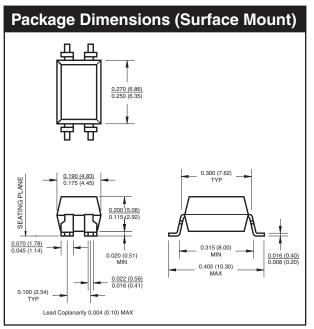


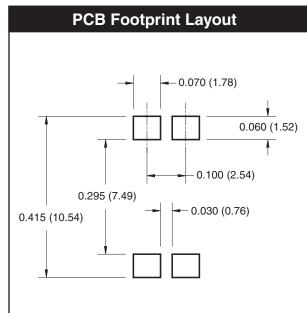


H11B815 4-Pin Photodarlington Optocoupler

0.016 (0.40)
0.008 (0.20)







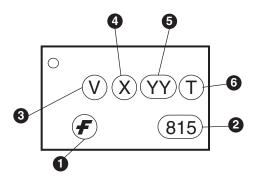
NOTE

All dimensions are in inches (millimeters)

Ordering Information

Option	Order Entry Identifier	Description
S	.S	Surface Mount Lead Bend
SD	.SD	Surface Mount; Tape and reel
W	.W	0.4" Lead Spacing
300	.300	VDE 0884
300W	.300W	VDE 0884, 0.4" Lead Spacing
3S	.3S	VDE 0884, Surface Mount
3SD	.3SD	VDE 0884, Surface Mount, Tape & Reel

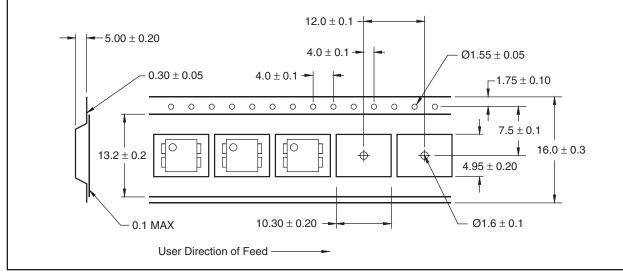
Marking Information



Definiti	Definitions				
1	Fairchild logo				
2	Device number				
3	VDE mark (Note: Only appears on parts ordered with VDE option – See order entry table)				
4	One digit year code				
5	Two digit work week ranging from '01' to '53'				
6	Assembly package code				

H11B815 4-Pin Photodarlington Optocoupler

Carrier Tape Specifications



NOTE

All dimensions are in millimeters

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EnSigna™	ImpliedDisconnect [™]	OCXPro™	SILENT SWITCHER [®]	Wire™
FACT™	IntelliMAX™	OPTOLOGIC [®]	SMART START™	
FACT Quiet Serie		OPTOPLANAR™	SPM™	
Aarooo the hear	A round the world TM	PACMAN™	Stealth™	
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Programmable P		PowerEdge™	SuperSOT™-6	

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PRODUCT STATUS DEFINITIONS

Definition of Terms

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Preliminary	First Production	This datasheet contains preliminary data, and supplementary data will be published at a later date. Fairchild Semiconductor reserves the right to make changes at any time without notice in order to improve design.
No Identification Needed	Full Production	This datasheet contains final specifications. Fairchild Semiconductor reserves the right to make changes at any time without notice in order to improve design.
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